

S/N 09/883795

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes et al.

Examiner: Theresa Doan

Serial No.: 09/883795

Group Art Unit: 2814

Filed: June 18, 2001

Docket No.: 303.355US4

METHOD OF FORMING A DEVICE WITH A GALLIUM NITRIDE OR
GALLIUM ALUMINUM NITRIDE GATE (as amended)

AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

In response to the Office Action dated 22 October 2003, the applicant requests reconsideration of the above-identified application in view of the following. Please amend the application as follows.



IN THE TITLE

Please amend the title as follows:

~~DEAPROM AND TRANSISTOR~~ METHOD OF FORMING A DEVICE WITH A GALLIUM NITRIDE OR GALLIUM ALUMINUM NITRIDE GATE